



MOSFET Module Nomenclature

MD

MD=MOSFET Module

200

Nominal Current

$I_b(@T_c=25^\circ\text{C})$ as e.g. 200=200A

HB

Circuit Configuration

- SG=Single
- CU=Chopper Diode Up Side
- CL=Chopper Diode Low Side
- HA=Asymmetrical Bridge
- HF=Half Bridge
- HB=Half Bridge + Brake
- HT=Tri-Pack
- HH=H Bridge
- FF=3 Phase Bridge
- FB=3 Phase Bridge + Brake

N

Die Characteristics

- N=Planar MOSFET
- M=Trench MOSFET

60

Voltage e.g. 60=60V

B2

Package Type

- B1=73mmx41mmx18mm, Cu Base
- B2=93mmx40mmx17mm, Cu Base
- B3=108mmx62mmx22mm, Cu Base
- B4=93mmx62mmx17mm, Cu Base
- B5=110mmx90mmx35mm, Cu Base

S

Screening Level

P=Unscreened, 25°C Electrical Test (Not for Qualification)

S=Screened for Industrial Applications

H=Screened for High Reliability Applications